TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

2SC3112

For Audio Amplifier and Switching Applications

Unit: mm

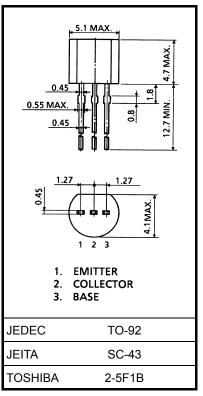
High DC current gain: hFE = 600~3600
 High breakdown voltage: VCEO = 50 V

• High collector current: IC = 150 mA (max)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	50	V
Collector-emitter voltage	V _{CEO}	50	V
Emitter-base voltage	V _{EBO}	5	V
Collector current	IC	150	mA
Base current	ΙΒ	30	mA
Collector power dissipation	PC	400	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	-55~125	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.



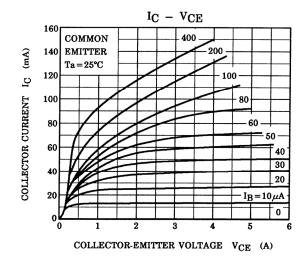
Weight: 0.21 g (typ.)

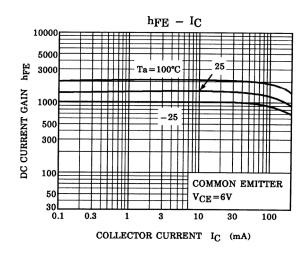
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

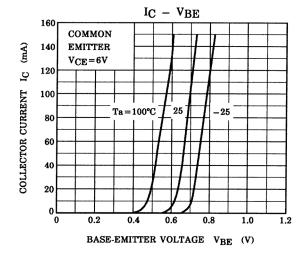
Electrical Characteristics (Ta = 25°C)

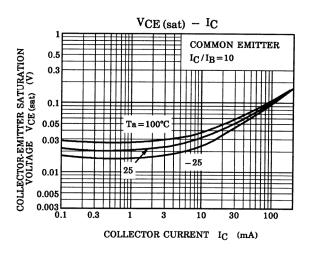
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit	
Collector cut-off current	I _{CBO}	V _{CB} = 50 V, I _E = 0	_	_	0.1	μА	
Emitter cut-off current	I _{EBO}	V _{EB} = 5 V, I _C = 0	_	_	0.1	μА	
DC current gain	h _{FE} (Note)	$V_{CE} = 6 \text{ V}, I_C = 2 \text{ mA}$	600	_	3600		
Collector-emitter saturation voltage	V _{CE} (sat)	$I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$	_	0.12	0.25	V	
Transition frequency	f _T	V _{CE} = 10 V, I _C = 10 mA	100	250	_	MHz	
Collector output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	3.5	_	pF	
Noise figure	NF (1)	$\begin{aligned} &V_{CE}=6 \text{ V, I}_{C}=0.1 \text{ mA, f}=100 \text{ Hz,} \\ &R_{G}=10 \text{ k}\Omega \end{aligned}$	_	0.5	_	dB	
	NF (2)	$\begin{split} &V_{CE}=6~V,~I_{C}=0.1~\text{mA, f}=1~\text{kHz},\\ &R_{G}=10~\text{k}\Omega \end{split}$	_	0.3		uБ	

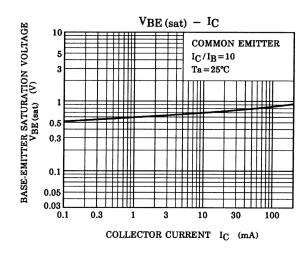
Note: h_{FE} classification A: 600~1800, B: 1200~3600

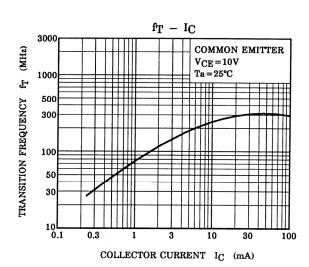


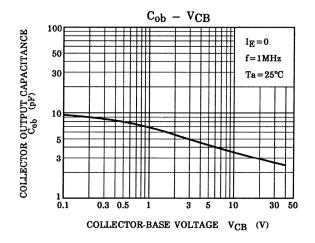


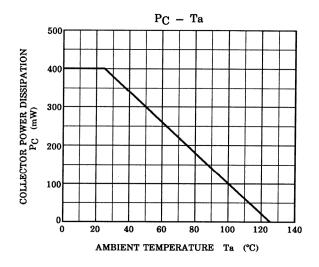












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20070701-EN GENERAL

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